VN330SP(8932)

QUAD HIGH SIDE SMART POWER SOLID STATE RELAY

General Features

Type	V_{demag}(*)	R_{DSon}(*)	I_{out}(*)	V_{CC}
VN330SP(8932)	V_{CC}-55V	0.32Ω(**)	1A	36V

(*)Per channel.

(**)at TJ = 85 °C

PowerSO-10™

Features

- OUTPUT CURRENT : 1A PER CHANNEL
- DIGITAL INPUT CLAMPED AT 32V MINIMUM VOLTAGE
- SHORTED LOAD AND OVER-TEMPERATURE PROTECTIONS
- BUILT-IN CURRENT LIMITER
- UNDERVOLTAGE SHUT-DOWN
- OPEN DRAIN DIAGNOSTIC OUTPUT
- FAST DEMAGNETIZATION OF INDUCTIVE LOADS

Description

The VN330SP(8932) is a monolithic device made using STMicroelectronics VIPower Technology, intended for driving four indipendent resistive or inductive loads with one side connected to ground. Active current limitation avoids dropping the system power supply in case of shorted load. Built-in thermal shut-down protects the chip from overtemperature and short circuit. The open drain diagnostic output indicates over-temperature conditions.

Block Diagram

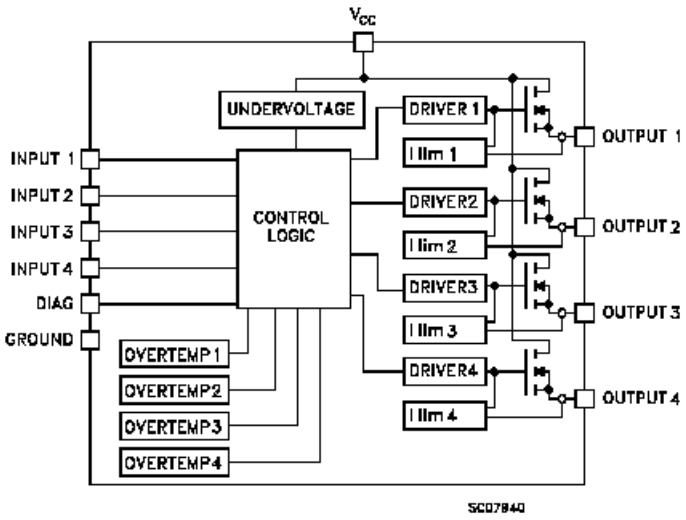


Table 1. Absolute Maximum Rating

Symbol	Parameter	Value	Unit
V_{CC}	Power supply voltage	45	V
$-V_{CC}$	Reverse supply voltage	-0.3	V
I_{OUT}	Output current (continuos)	Internally limited	A
I_R	Reverse output current (per channel)	-6	A
I_{IN}	Input current (per channel)	± 10	mA
I_{DIAG}	Diag pin current	± 10	mA
V_{ESD}	Electrostatic discharge (R = 1.5KW; C = 100pF)	2000	V
E_{AS}	Single pulse avalanche energy per channel not simultaneously *Figure 3.*	400	mJ
P_{tot}	Power dissipation at T_c <= 25°C	Internally limited	W
TJ	Junction operating temperature	Internally limited	°C
T_{stg}	Storage Temperature	-55 to 150	°C

Figure 1. Connection Diagram (Top View)

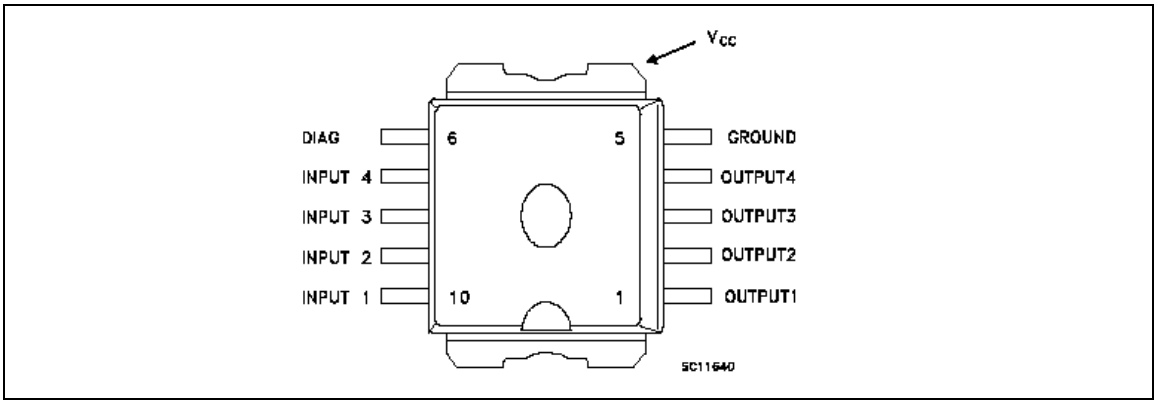


Figure 2. Current and Voltage Conventions

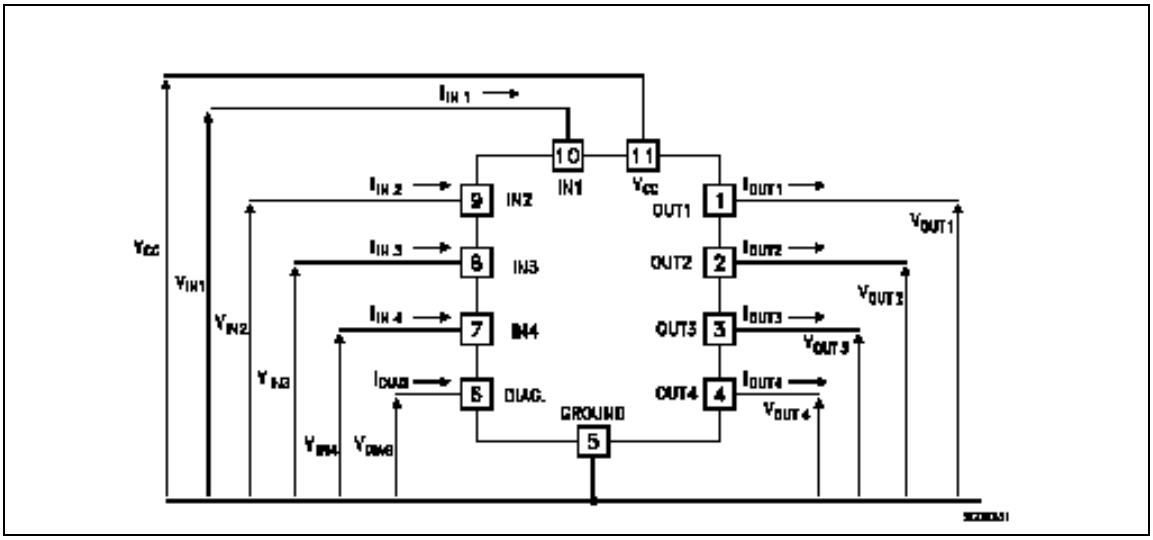


Table 2. Thermal data

Symbol	Parameter		Max Value	Unit
R_{thJC}	Thermal resistance junction-case (*Note:1*)	Max	2	°C/W
R_{thJA}	Thermal resistance junction-ambient (*Note:2*)	Max	50	°C/W

Note: 1.Per channel

Note: 2.When mounted using minimum recommended pad size on FR-4 board

Electrical Chracteristics (10V < V_{CC} < 36V; -25°C < T_J < 125°C; unless otherwise specified)

Table 3. Power Section

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{CC}	Supply voltage		10		36	V
R_{ON}	On state resistance	I_{OUT} = 0.5A; T_J = 125°C I_{OUT} = 0.5A; T_J = 85°C I_{OUT} = 0.5A; T_J = 25°C			0.4 0.32 0.2	Ω Ω Ω
I_S	Supply current	All channels OFF; V_{IN} = 30V; On state; T_J = 125°C $I_{OUT1...}I_{OUT4}$ = 0V			1 10	mA mA
V_{demag}	Output voltage at turn-off	I_{OUT} = 0.5A; L_{LOAD} >= 1mH	V_{CC}-65	V_{CC}-55	V_{CC}-45	V

Table 4. Logical Input

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{IL}	Input low level voltage				2	V
V_{IH}	Input high level voltage .	*Note:3*	3.5			V
$V_{I(HYST)}$	Input hysteresis voltage			0.5		V
I_{IN}	Input current	V_{IN} = 0 to 30V V_{IN} = 0 to 2V	 25		600	µA µA
I_{LGND}	Output current in ground disconnection	V_{CC} = V_{INn} = GND = DIAG = 24V; TJ = 25°C			25	mA
V_{ICL}	Input clamp voltage *Note:3*	I_{IN} = 1mA I_{IN} = -1mA	32	36 -0.7		V V

Note: 3.The input voltage is internally clamped at 32V minimum, it is possible to connect the input pins to an higher voltage via an external resistor calculate to not exceed 10mA

Table 5. Switching (V_{CC} = 24V)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$t_{d(ON)}$	Turn-on delay time of Output current	I_{OUT} = 0.5A, Resistive Load Input rise time < 0.1µs, T_J = 25°C T_J = 125°C		30	40 60	µs µs
t_r	Rise time of Output current	I_{OUT} = 0.5A, Resistive Load Input rise time < 0.1µs, T_J = 25°C T_J = 125°C		50	100 115	µs µs
$t_{d(OFF)}$	Turn-off delay time of Output current	I_{OUT} = 0.5A, Resistive Load Input rise time < 0.1µs, T_J = 25°C T_J = 125°C		20	30 40	µs µs
t_f	Fall time of Output current	I_{OUT} = 0.5A, Resistive Load Input rise time < 0.1µs, T_J = 25°C T_J = 125°C		8	15 20	µs µs
$(di/dt)_{on}$	Turn-on current slope	I_{OUT} = 0.5A, I_{OUT} = I_{LIM}, T_J = 25°C			0.5 2	A/µs A/µs
$(di/dt)_{off}$	Turn-off current slope	I_{OUT} = 0.5A, I_{OUT} = I_{LIM}, T_J = 25°C			2 4	A/µs A/µs

Table 6. Protections

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{DIAG}(*)	Status voltage output low	I_{DIAG} = 5mA (Fault condition)			1	V
V_{SCL}(*)	Status clamp voltage	I_{DIAG} = 1mA I_{DIAG} = -1mA	32	36 -0.7		V V
V_{USD}	Undervoltage shut down		5		8	V
I_{LIM}	DC Short circuit current	V_{CC} = 24V; R_{LOAD} < 10mΩ	1		2.5	A
I_{OVPK}	Peak short circuit current	V_{CC} = 24V; V_{IN} = 30; R_{LOAD} < 10mΩ			4	A
I_{DIAGH}	Leakage on diag pin in high state	V_{DIAG} = 24V			100	µA
I_{LOAD}	Output leakage current	V_{CC} = 10 to 36V; V_{IN} = V_{IL} 4 Channels in Parallel			25	µA
t_{SC}	Delay time of current limiter				100	µs
T_{TSD}	Thermal shut down temperature		150	170		°C
T_R	Thermal reset temperature		135	155		°C

(*)Status determination > 100ms after the switching edge.

Note: If INPUT pin is floating the corrisponding channel will automatically switch OFF. If GND pin is disconnected, the channel will switch OFF provided VCC not exceed 36V.

Figure 3. Avalance Energy Test Circuit

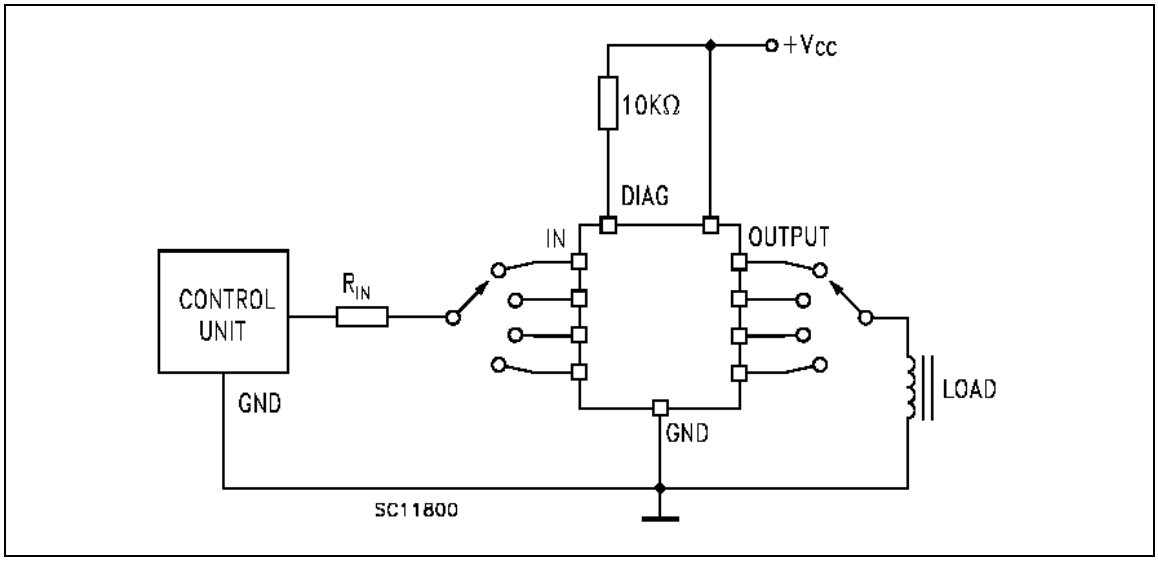


Figure 4. Peak Short Circuit Test Diagram

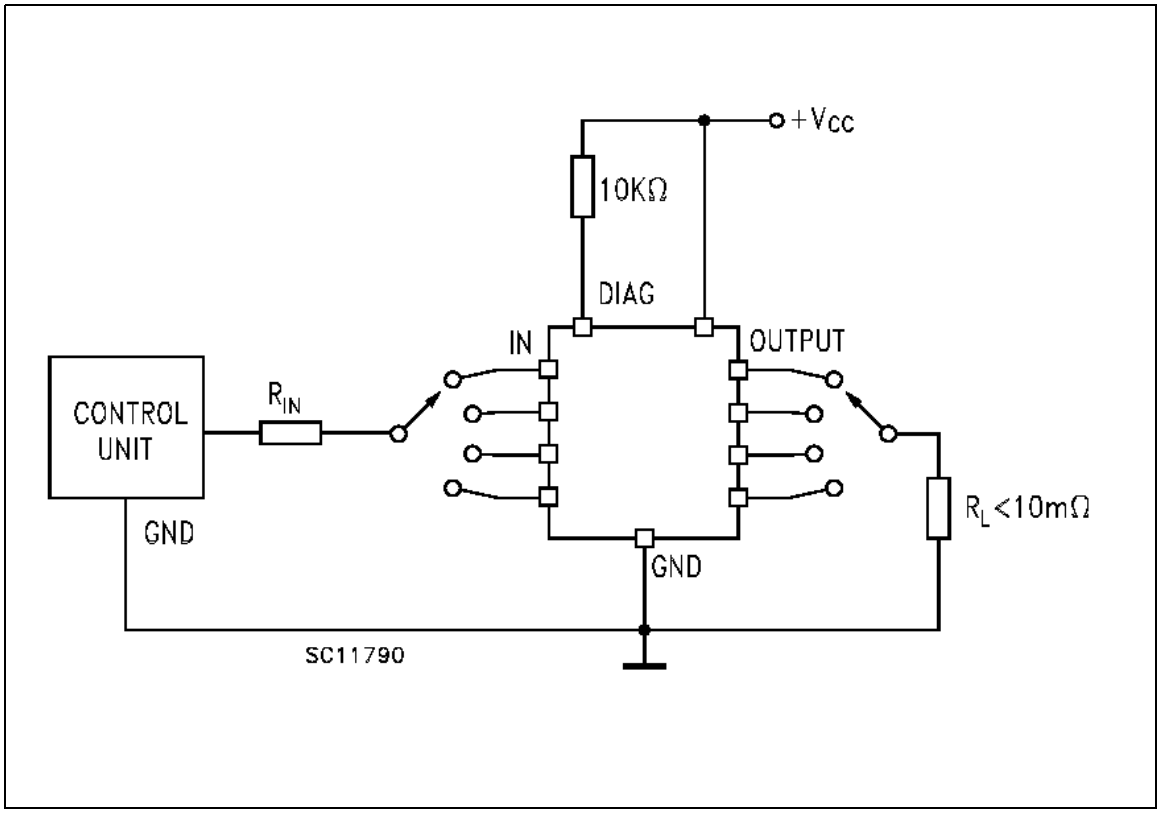


Table 7. Truth Table

Conditions	INPUTn	OUTPUTn	Diagnostic
Normal operation	L H	L H	H H
Overtemperature	L H	L L	H L
Undervoltage	L H	L L	H H
Shorted load (Current limitation)	L H	L H	H H

Figure 5. Switching Waveforms

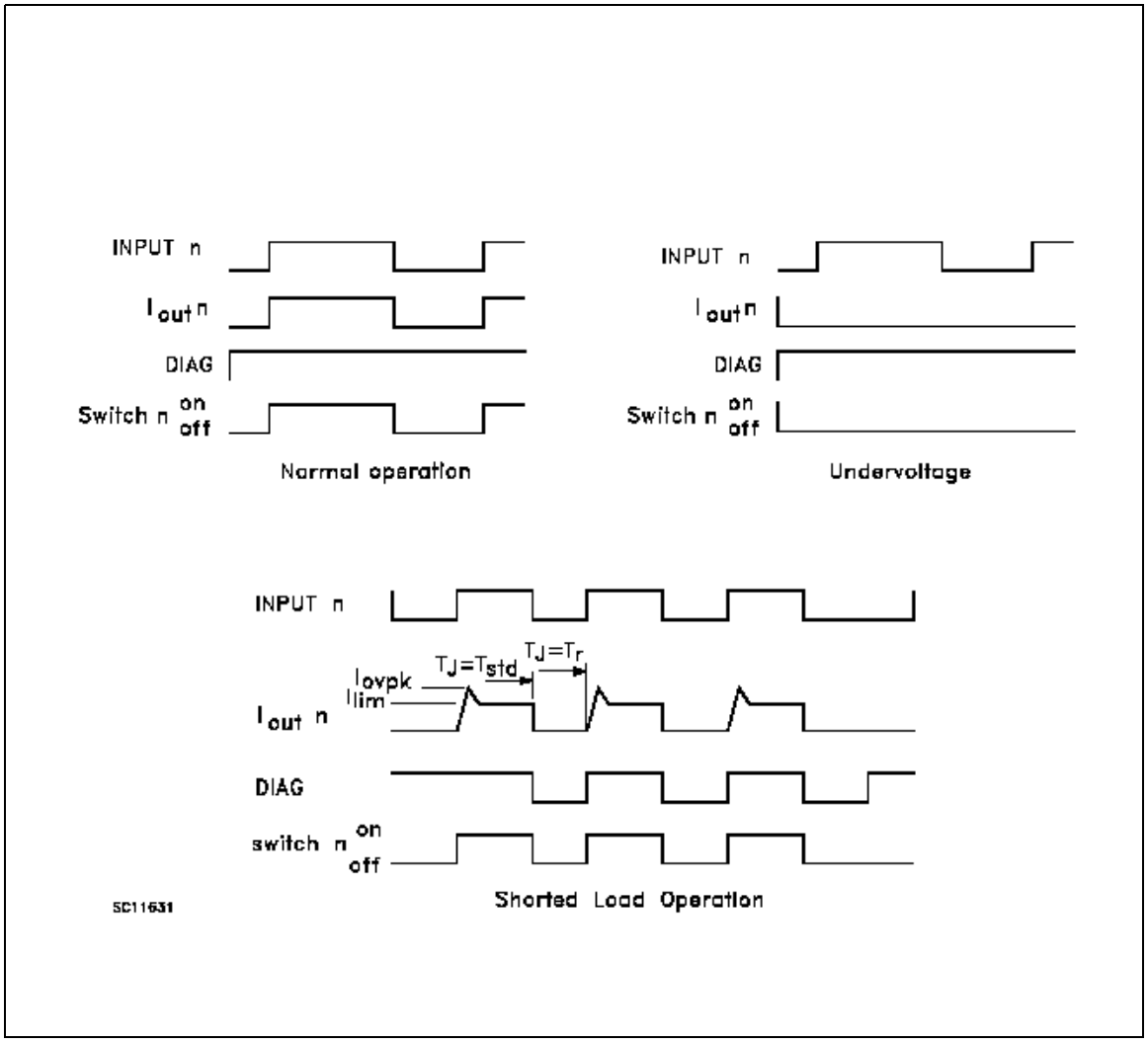


Figure 6. Switching Parameter Test Conditions

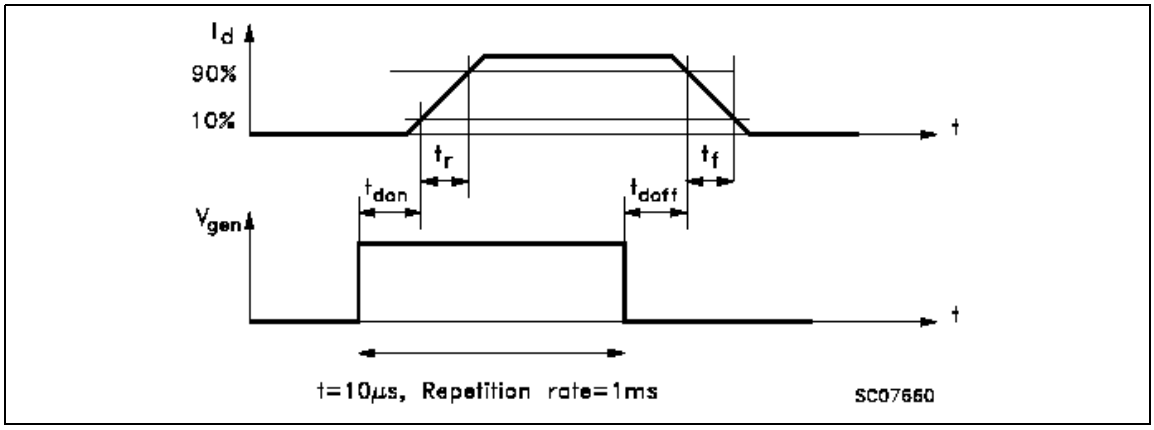
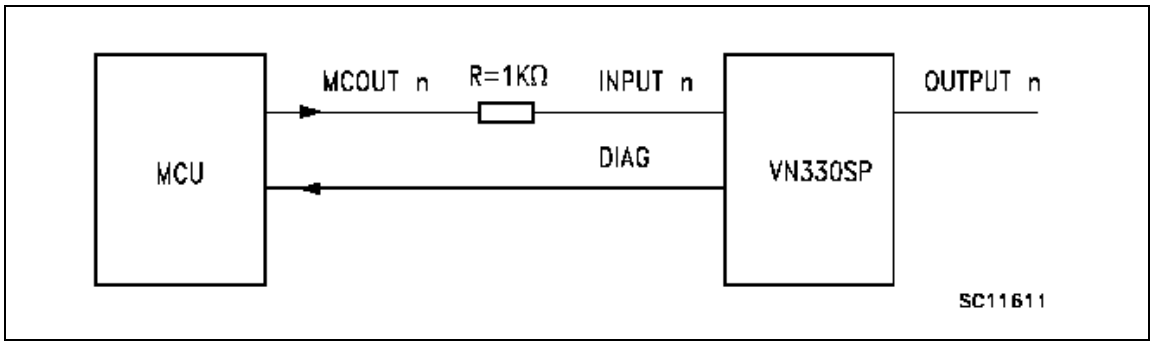
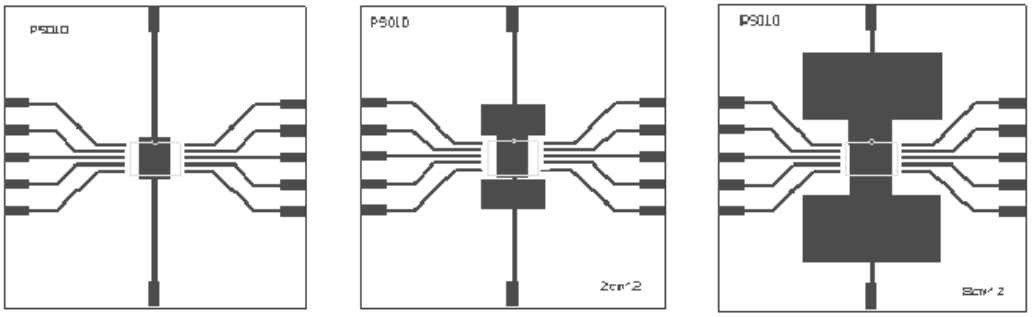


Figure 7. Driving Circuit



PowerSO-10™ Thermal Data

Figure 8. PowerSO-10™ PC Board



Layout condition of R_{th} and Z_{th} measurements (PCB FR4 area= 58mm x 58mm, PCB thickness=2mm, Cu thickness=35µm, Copper areas: from minimum pad lay-out to 8cm^2).

Figure 9. R_{thJA} Vs. PBC copper area in open box free air condition

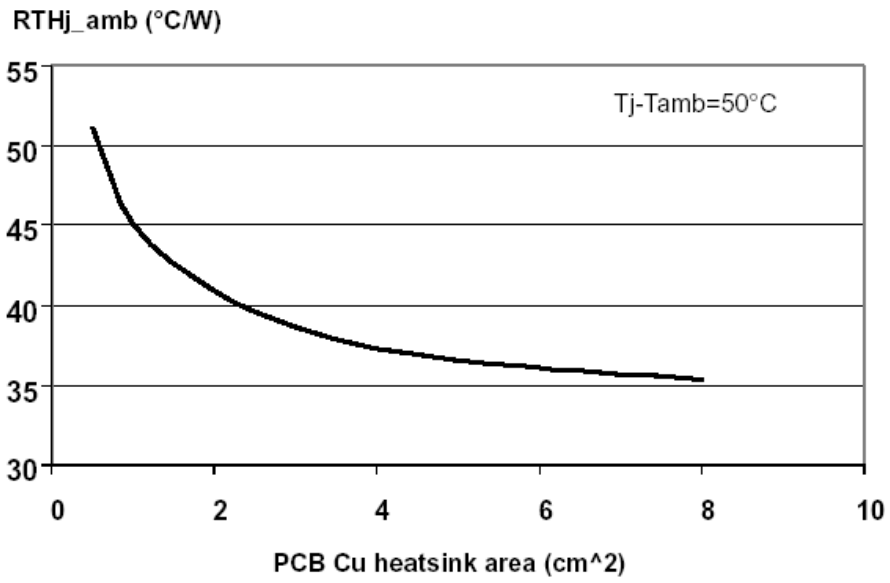


Table 8. PowerSO-10™ Mechanical Data

Symbol	millimeters		
	Min	Typ	Max
A	3.35		3.65
A (*)	3.4		3.6
A1	0.00		0.10
B	0.40		0.60
B (*)	0.37		0.53
C	0.35		0.55
C (*)	0.23		0.32
D	9.40		9.60
D1	7.40		7.60
E	9.30		9.50
E2	7.20		7.60
E2 (*)	7.30		7.50
E4	5.90		6.10
E4 (*)	5.90		6.30
e		1.27	
F	1.25		1.35
F (*)	1.20		1.40
H	13.80		14.40
H (*)	13.85		14.35
h		0.50	
L	1.20		1.80
L (*)	0.80		1.10
a	0°		8°
α (*)	2°		8°

Note: (*) Muar only POA P013P

Figure 10. PowerSO-10™ Package Dimensions

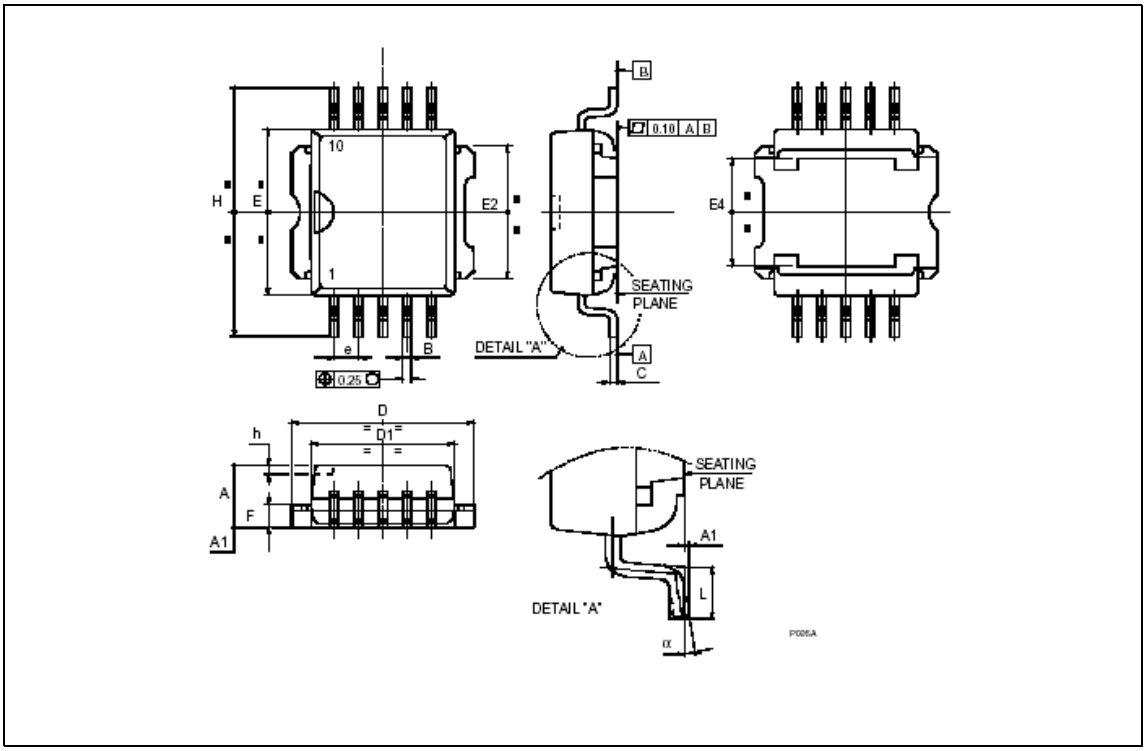
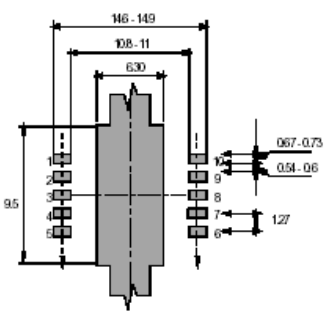
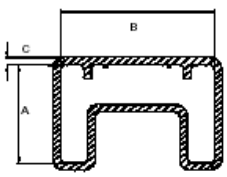
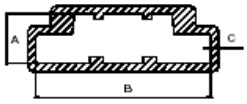


Figure 11. PowerSO-10™ Suggested Pad and Tube Shipment (No Suffix)





CASABLANCA

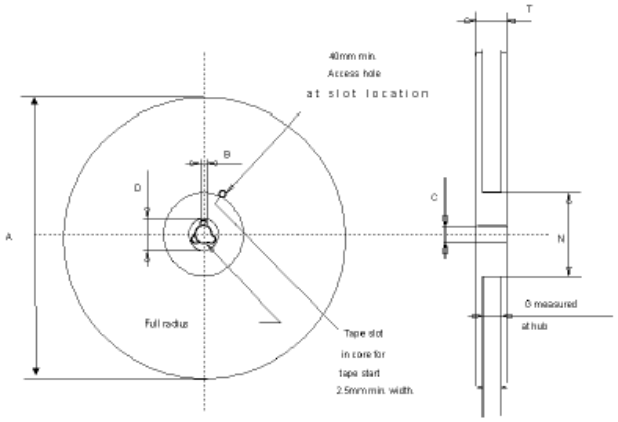


MUAR

All dimensions are in mm.

	Base Q.ty	Bulk Q.ty	Tube length (± 0.5)	A	B	C (± 0.1)
Casablanca	50	1000	532	10.4	16.4	0.8
Muar	50	1000	532	4.9	17.2	0.8

Figure 12. Tape and Reel Shipment (Suffix "TR")



REEL DIMENSIONS

Base Q.ty	600
Bulk Q.ty	600
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G (+ 2 / -0)	24.4
N (min)	60
T (max)	30.4

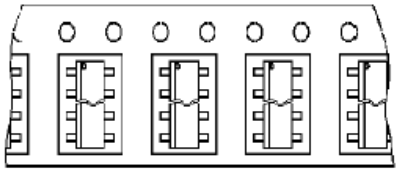
All dimensions are in mm.

TAPE DIMENSIONS

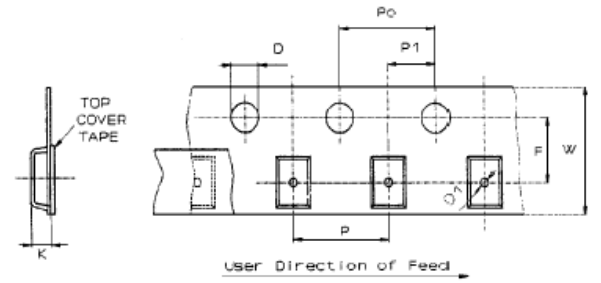
According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb. 1986

Tape width	W	24
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	24
Hole Diameter	D (± 0.1/-0)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	11.5
Compartment Depth	K (max)	6.5
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.



User Direction of Feed



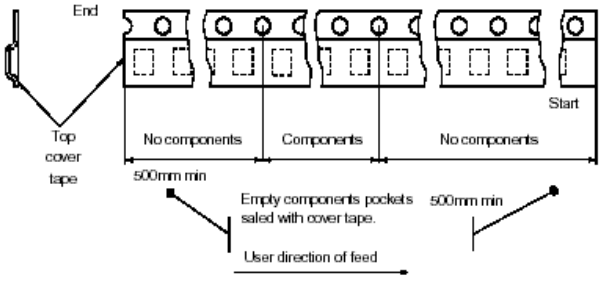


Table 9. Order Codes

Package	Tube	Tape and Reel
PowerSO-10™	VN330SP(8932)	VN330SP(8932)TR

Table 10. Revision History

Date	Revision	Changes
5-Sep-2005	2	New Template. Final release